

# Dual Bipolar/JFET, Audio Operational Amplifier

**OP275** 

#### **FEATURES**

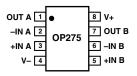
**Excellent Sonic Characteristics** 

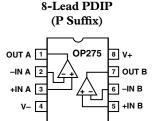
Low Noise: 6 nV/\Hz
Low Distortion: 0.0006%
High Slew Rate: 22 V/μs
Wide Bandwidth: 9 MHz
Low Supply Current: 5 mA
Low Offset Voltage: 1 mV
Low Offset Current: 2 nA
Unity Gain Stable
SOIC-8 Package
PDIP-8 Package

APPLICATIONS
High Performance Audio
Active Filters
Fast Amplifiers
Integrators

#### PIN CONNECTIONS

8-Lead Narrow-Body SOIC (S Suffix)





#### **GENERAL DESCRIPTION**

The OP275 is the first amplifier to feature the Butler Amplifier front end. This new front end design combines both bipolar and JFET transistors to attain amplifiers with the accuracy and low noise performance of bipolar transistors, and the speed and sound quality of JFETs. Total Harmonic Distortion plus Noise equals that of previous audio amplifiers, but at much lower supply currents.

A very low l/f corner of below 6 Hz maintains a flat noise density response. Whether noise is measured at either 30 Hz or 1 kHz, it is only 6 nV $\sqrt{\rm Hz}$ . The JFET portion of the input stage gives the OP275 its high slew rates to keep distortion low, even when large output swings are required, and the 22 V/ $\mu$ s slew rate of the OP275 is the fastest of any standard audio amplifier. Best of all, this low noise and high speed are accomplished using less than 5 mA of supply current, lower than any standard audio amplifier.

Improved dc performance is also provided with bias and offset currents greatly reduced over purely bipolar designs. Input offset voltage is guaranteed at 1 mV and is typically less than 200  $\mu V$ . This allows the OP275 to be used in many dc-coupled or summing applications without the need for special selections or the added noise of additional offset adjustment circuitry.

The output is capable of driving  $600~\Omega$  loads to 10~V rms while maintaining low distortion. THD + Noise at 3~V rms is a low 0.0006%.

The OP275 is specified over the extended industrial (-40°C to +85°C) temperature range. OP275s are available in both plastic DIP and SOIC-8 packages. SOIC-8 packages are available in 2500-piece reels. Many audio amplifiers are not offered in SOIC-8 surface-mount packages for a variety of reasons; however, the OP275 was designed so that it would offer full performance in surface-mount packaging.

#### REV.C

# **OP275-SPECIFICATIONS**

# **ELECTRICAL CHARACTERISTICS** (@ $V_S = \pm 15.0$ V, $T_A = 25^{\circ}$ C, unless otherwise noted.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
AUDIO PERFORMANCE THD + Noise		V - 2V				
THD + Noise		$V_{IN} = 3 \text{ V rms},$ $R_L = 2 \text{ k}\Omega, f = 1 \text{ kHz}$		0.006		%
Voltage Noise Density	e <sub>n</sub>	f = 30  Hz		7		$nV\sqrt{Hz}$
-		f = 1  kHz		6		$nV\sqrt{Hz}$
Current Noise Density	i <sub>n</sub>	f = 1 kHz		1.5		$pA\sqrt{Hz}$
Headroom		THD + Noise $\leq 0.01\%$ , $R_L = 2 \text{ k}\Omega, V_S = \pm 18 \text{ V}$		>12.9		dBu
INPUT CHARACTERISTICS						
Offset Voltage	Vos				1	mV
I P' C	_	$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$		100	1.25	mV
Input Bias Current	$I_{\rm B}$	$V_{CM} = 0 V$ $V_{CM} = 0 V, -40^{\circ}C \le T_{A} \le +85^{\circ}C$		100 100	350 400	nA nA
Input Offset Current	I <sub>OS</sub>	$V_{CM} = 0 V, -40 C \le I_A \le +85 C$ $V_{CM} = 0 V$		2	50	nA
	-03	$V_{CM} = 0 \text{ V}, -40^{\circ}\text{C} \le T_{A} \le +85^{\circ}\text{C}$		2	100	nA
Input Voltage Range	$V_{CM}$		-10.5		+10.5	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 10.5 \text{ V},$	00	106		100
Large Signal Voltage Gain	A <sub>VO</sub>	$ -40^{\circ}C \le T_{A} \le +85^{\circ}C  R_{I} = 2 k\Omega $	80 250	106		dB V/mV
Large Signal voltage Gain	AVO	$R_{L} = 2 k\Omega$ $R_{L} = 2 k\Omega$ , $-40^{\circ}$ C $\leq T_{A} \leq +85^{\circ}$ C	175			V/mV
		$R_L = 600 \Omega$		200		V/mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$			2		μV/°C
OUTPUT CHARACTERISTICS						
Output Voltage Swing	Vo	$R_{L} = 2 k\Omega$	-13.5	±13.9	+13.5	V
		$R_{L} = 2 \text{ k}\Omega, -40^{\circ}\text{C} \le T_{A} \le +85^{\circ}\text{C}$ $R_{L} = 600 \Omega, V_{S} = \pm 18 \text{ V}$	-13	±13.9 +14, -16	+13	V
POWER SUPPLY		1C = 000 12, VS = ±10 V		114,-10		<b>, ,</b>
Power Supply Rejection Ratio	PSRR	$V_S = \pm 4.5 \text{V} \text{ to } \pm 18 \text{V}$	85	111		dB
1 o not supply 10,000001 1 tutte	1014	$V_S = \pm 4.5 \text{ V to } \pm 18 \text{ V},$				
		$-40$ °C $\leq T_A \leq +85$ °C	80			dB
Supply Current	$I_{SY}$	$V_S = \pm 4.5 \text{ V to } \pm 18 \text{ V}, V_O = 0 \text{ V},$		4	_	
		$R_{L} = \infty, -40^{\circ}\text{C} \le T_{A} \le +85^{\circ}\text{C}$ $V_{S} = \pm 22 \text{ V}, V_{O} = 0 \text{ V}, R_{L} = \infty,$		4	5	mA
		$\sqrt{8 - \pm 22}$ v, $\sqrt{6 - 6}$ v, $\sqrt{6 - 8}$ v, $\sqrt{6 - 6}$ v, $\sqrt{6 - 8}$ v			5.5	mA
Supply Voltage Range	$V_{S}$	n in the second	±4.5		±22	V
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 2 k\Omega$	15	22		V/µs
Full-Power Bandwidth	BW <sub>P</sub> GBP			9		kHz
Gain Bandwidth Product Phase Margin	$\emptyset_{\rm m}$			9 62		MHz Degrees
Overshoot Factor	√ m	$V_{IN} = 100 \text{ mV}, A_V = +1,$		02		Degrees
		$R_{L} = 600 \Omega, C_{L} = 100 \text{ pF}$		10		%

Specifications subject to change without notice.

#### ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

Package Type	$\theta_{\mathrm{IA}}^{4}$	$\theta_{IC}$	Unit
Lead Temperature Range	(Soldering, 6	60 sec)	300°C
P, S Packages		–65°C	to +150°C
Junction Temperature Ra	0		
OP275G		40°	C to +85°C
Operating Temperature R	0		
P, S Packages		65°C	to +150°C
Storage Temperature Ran	0		
Output Short-Circuit Du	ıration to GN	$\mathbb{D}^3$	. Indefinite
Differential Input Voltage			
Input Voltage <sup>2</sup>			
Supply Voltage			

Package Type	$\theta_{\mathrm{JA}}^{}4}$	$\theta_{ m JC}$	Unit
8-Lead Plastic DIP (P)	103	43	°C/W
8-Lead SOIC (S)	158	43	°C/W

#### NOTES

#### **ORDERING GUIDE**

Model	Temperature Range	Package Description	Package Option
OP275GP	-40°C to +85°C	8-Lead PDIP	N-8
OP275GS	−40°C to +85°C	8-Lead SOIC	R-8
OP275GS-REEL	−40°C to +85°C	8-Lead SOIC	R-8
OP275GS-REEL7	−40°C to +85°C	8-Lead SOIC	R-8
OP275GSZ*	−40°C to +85°C	8-Lead SOIC	R-8
OP275GSZ-REEL*	−40°C to +85°C	8-Lead SOIC	R-8
OP275GSZ-REEL7*	−40°C to +85°C	8-Lead SOIC	R-8

<sup>\*</sup>Z = Pb-free part.

#### CAUTION \_

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000V readily accumulate on the human body and test equipment and can discharge without detection. Although the OP275 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



REV. C –3–

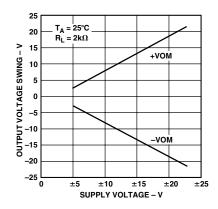
<sup>&</sup>lt;sup>1</sup>Absolute maximum ratings apply to packaged parts, unless otherwise noted.

 $<sup>^2</sup>$ For supply voltages greater than  $\pm 22$ V, the absolute maximum input voltage is equal to the supply voltage.

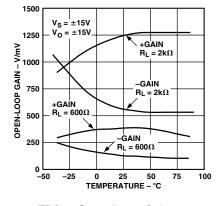
<sup>&</sup>lt;sup>3</sup>Shorts to either supply may destroy the device. See data sheet for full details.

 $<sup>^4\</sup>theta_{JA}$  is specified for the worst-case conditions, i.e.,  $\theta_{JA}$  is specified for device in socket for PDIP packages;  $\theta_{JA}$  is specified for device soldered in circuit board for SOIC packages.

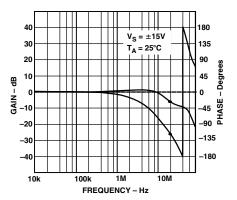
# **OP275—Typical Performance Characteristics**



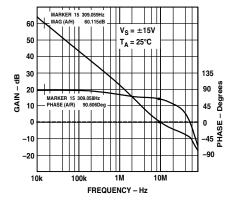
TPC 1. Output Voltage Swing vs. Supply Voltage



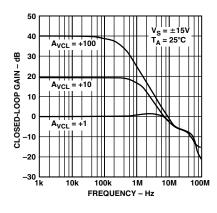
TPC 2. Open-Loop Gain vs. Temperature



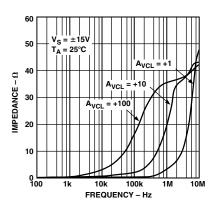
TPC 3. Closed-Loop Gain and Phase,  $A_V = +1$ 



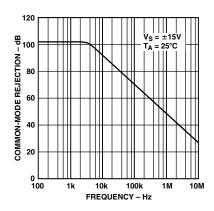
TPC 4. Open-Loop Gain, Phase vs. Frequency



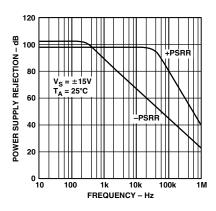
TPC 5. Closed-Loop Gain vs. Frequency



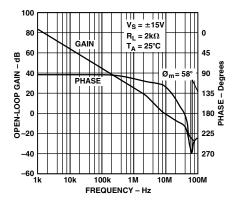
TPC 6. Closed-Loop Output Impedance vs. Frequency



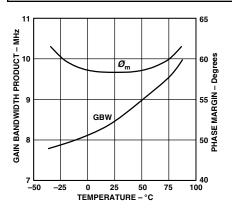
TPC 7. Common-Mode Rejection vs. Frequency



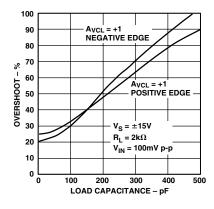
TPC 8. Power Supply Rejection vs. Frequency



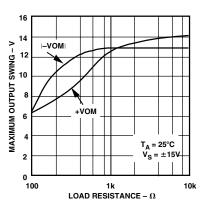
TPC 9. Open-Loop Gain, Phase vs. Frequency



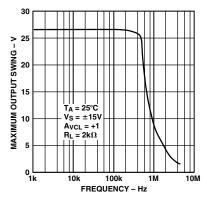
TPC 10. Gain Bandwidth Product, Phase Margin vs. Temperature



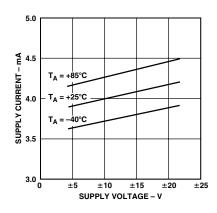
TPC 11. Small Signal Overshoot vs. Load Capacitance



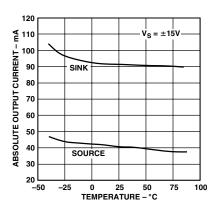
TPC 12. Maximum Output Voltage vs. Load Resistance



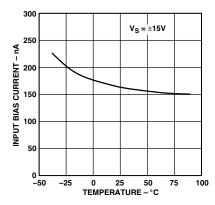
TPC 13. Maximum Output Swing vs. Frequency



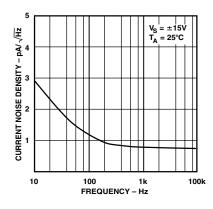
TPC 14. Supply Current vs. Supply Voltage



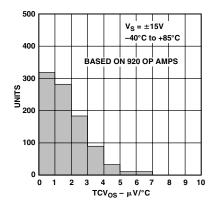
TPC 15. Short-Circuit Current vs. Temperature



TPC 16. Input Bias Current vs. Temperature

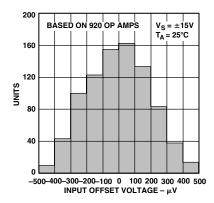


TPC 17. Current Noise Density vs. Frequency

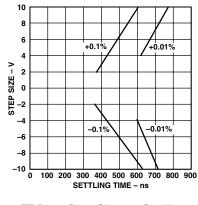


TPC 18. TCV<sub>OS</sub> Distribution

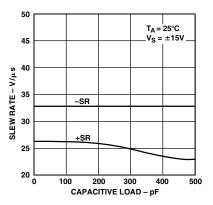
REV. C –5–



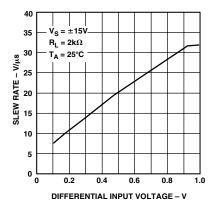
TPC 19. Input Offset ( $V_{OS}$ ) Distribution



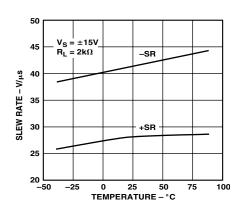
TPC 20. Step Size vs. Settling Time



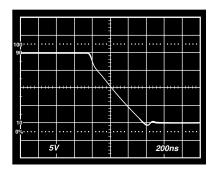
TPC 21. Slew Rate vs. Capacitive Load



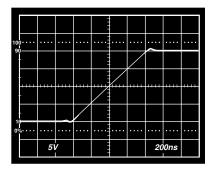
TPC 22. Slew Rate vs. Differential Input Voltage



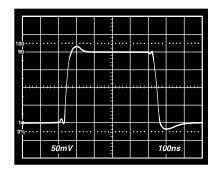
TPC 23. Slew Rate vs. Temperature



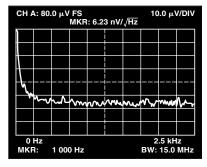
TPC 24. Negative Slew Rate  $R_L = 2 \text{ k}\Omega$  ,  $V_S = \pm 15 \text{ V}$ ,  $A_V = +1$ 



TPC 25. Positive Slew Rate  $R_L = 2 k\Omega$ ,  $V_S = \pm 15 V$ ,  $A_V = +1$ 



TPC 26. Small Signal Response  $R_L = 2 \text{ k}\Omega$  ,  $V_S = \pm 5 \text{ V}$ ,  $A_V = +1$ 



TPC 27. Voltage Noise Density vs. Frequency  $V_S = \pm 15 V$ 

–6– REV. C

#### **APPLICATIONS**

#### **Circuit Protection**

OP275 has been designed with inherent short-circuit protection to ground. An internal 30  $\Omega$  resistor, in series with the output, limits the output current at room temperature to  $I_{SC}+$  = 40 mA and  $I_{SC}-$  = –90 mA, typically, with  $\pm15\,V$  supplies.

However, shorts to either supply may destroy the device when excessive voltages or currents are applied. If it is possible for a user to short an output to a supply for safe operation, the output current of the OP275 should be design-limited to  $\pm 30$  mA, as shown in Figure 1.

#### **Total Harmonic Distortion**

Total Harmonic Distortion + Noise (THD + N) of the OP275 is well below 0.001% with any load down to 600  $\Omega.$  However, this is dependent upon the peak output swing. In Figure 2, the THD + Noise with 3 V rms output is below 0.001%. In Figure 3, THD + Noise is below 0.001% for the 10 k $\Omega$  and 2 k $\Omega$  loads but increases to above 0.1% for the 600  $\Omega$  load condition. This is a result of the output swing capability of the OP275. Notice the results in Figure 4, showing THD versus  $V_{\rm IN}$  (V rms). This figure shows that the THD + Noise remains very low until the output reaches 9.5 V rms. This performance is similar to competitive products.

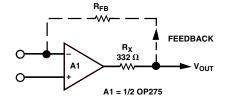


Figure 1. Recommended Output Short-Circuit Protection

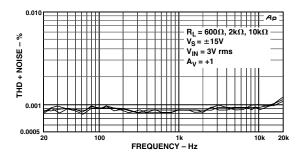


Figure 2. THD + Noise vs. Frequency vs. R<sub>LOAD</sub>

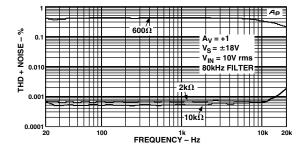


Figure 3. THD + Noise vs.  $R_{LOAD}$ ;  $V_{IN} = 10 \text{ V rms}$ 

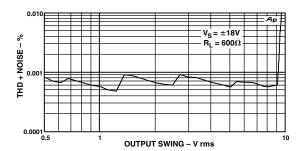


Figure 4. Headroom, THD + Noise vs. Output Amplitude (V rms);  $R_{LOAD} = 600 \Omega$ ,  $V_{SUP} = \pm 18 V$ 

The output of the OP275 is designed to maintain low harmonic distortion while driving 600  $\Omega$  loads. However, driving 600  $\Omega$  loads with very high output swings results in higher distortion if clipping occurs. A common example of this is in attempting to drive 10 V rms into any load with  $\pm 15$  V supplies. Clipping will occur and distortion will be very high. To attain low harmonic distortion with large output swings, supply voltages may be increased. Figure 5 shows the performance of the OP275 driving 600  $\Omega$  loads with supply voltages varying from  $\pm 18$  V to  $\pm 20$  V. Notice that with  $\pm 18$  V supplies the distortion is fairly high, while with  $\pm 20$  V supplies it is a very low 0.0007%.

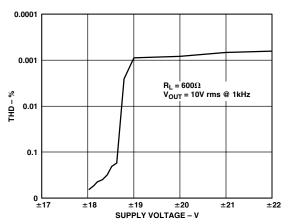


Figure 5. THD + Noise vs. Supply Voltage

#### Noise

The voltage noise density of the OP275 is below 7 nV/ $\sqrt{\text{Hz}}$  from 30 Hz. This enables low noise designs to have good performance throughout the full audio range. Figure 6 shows a typical OP275 with a 1/f corner at 2.24 Hz.

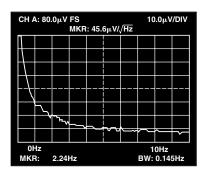


Figure 6. 1/f Noise Corner,  $V_S = \pm 15 V$ ,  $A_V = 1000$ 

REV. C -7-

#### **Noise Testing**

For audio applications, the noise density is usually the most important noise parameter. For characterization, the OP275 is tested using an Audio Precision, System One. The input signal to the Audio Precision must be amplified enough to measure it accurately. For the OP275, the noise is gained by approximately 1020 using the circuit shown in Figure 7. Any readings on the Audio Precision must then be divided by the gain. In implementing this test fixture, good supply bypassing is essential.

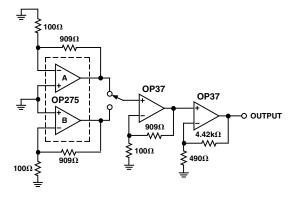


Figure 7. Noise Test Fixture

#### **Input Overcurrent Protection**

The maximum input differential voltage that can be applied to the OP275 is determined by a pair of internal Zener diodes connected across its inputs. They limit the maximum differential input voltage to  $\pm 7.5$  V. This is to prevent emitter-base junction breakdown from occurring in the input stage of the OP275 when very large differential voltages are applied. However, to preserve the OP275's low input noise voltage, internal resistances in series with the inputs were not used to limit the current in the clamp diodes. In small signal applications, this is not an issue; however, in applications where large differential voltages can be inadvertently applied to the device, large transient currents can flow through these diodes. Although these diodes have been designed to carry a current of  $\pm 5$  mA, external resistors as shown in Figure 8 should be used in the event that the OP275's differential voltage were to exceed  $\pm 7.5$  V.

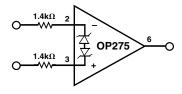


Figure 8. Input Overcurrent Protection

#### **Output Voltage Phase Reversal**

Since the OP275's input stage combines bipolar transistors for low noise and p-channel JFETs for high speed performance, the output voltage of the OP275 may exhibit phase reversal if either of its inputs exceeds its negative common-mode input voltage. This might occur in very severe industrial applications where a sensor or system fault might apply very large voltages on the inputs of the OP275. Even though the input voltage range of the OP275 is  $\pm 10.5$  V, an input voltage of approximately -13.5 V will cause output voltage phase reversal. In inverting amplifier configurations, the OP275's internal 7.5 V input clamping diodes will

prevent phase reversal; however, they will not prevent this effect from occurring in noninverting applications. For these applications, the fix is a simple one and is illustrated in Figure 9. A 3.92 k $\Omega$  resistor in series with the noninverting input of the OP275 cures the problem.

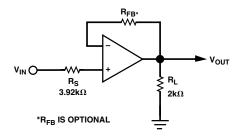


Figure 9. Output Voltage Phase Reversal Fix

#### Overload or Overdrive Recovery

Overload or overdrive recovery time of an operational amplifier is the time required for the output voltage to recover to a rated output voltage from a saturated condition. This recovery time is important in applications where the amplifier must recover quickly after a large abnormal transient event. The circuit shown in Figure 10 was used to evaluate the OP275's overload recovery time. The OP275 takes approximately 1.2 ms to recover to  $V_{\rm OUT}$  = +10 V and approximately 1.5 µs to recover to  $V_{\rm OUT}$  = -10 V.

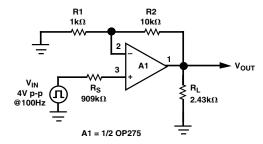


Figure 10. Overload Recovery Time Test Circuit

#### **Measuring Settling Time**

The design of OP275 combines a high slew rate and a wide gain bandwidth product to produce a fast settling ( $t_S < 1~\mu s$ ) amplifier for 8- and 12-bit applications. The test circuit designed to measure the settling time of the OP275 is shown in Figure 11. This test method has advantages over false-sum node techniques in that the actual output of the amplifier is measured, instead of an error voltage at the sum node. Common-mode settling effects are exercised in this circuit in addition to the slew rate and bandwidth effects measured by the false-sum node method. Of course, a reasonably flat-top pulse is required as the stimulus.

The output waveform of the OP275 under test is clamped by Schottky diodes and buffered by the JFET source follower. The signal is amplified by a factor of 10 by the OP260 and then Schottky-clamped at the output to prevent overloading the oscilloscope's input amplifier. The OP41 is configured as a fast integrator, which provides overall dc offset nulling.

#### **High Speed Operation**

As with most high speed amplifiers, care should be taken with supply decoupling, lead dress, and component placement. Recommended circuit configurations for inverting and noninverting applications are shown in Figures 12 and 13.

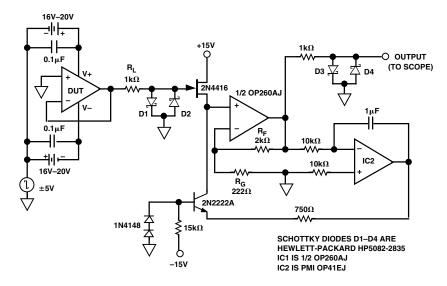


Figure 11. OP275's Settling Time Test Fixture

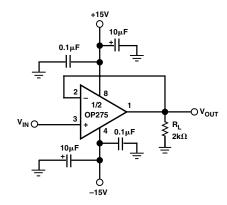


Figure 12. Unity Gain Follower

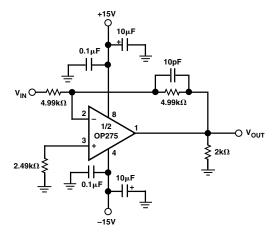


Figure 13. Unity Gain Inverter

In inverting and noninverting applications, the feedback resistance forms a pole with the source resistance and capacitance ( $R_S$  and  $C_S$ ) and the OP275's input capacitance ( $C_{\rm IN}$ ), as shown in Figure 14. With  $R_S$  and  $R_F$  in the kilohm range, this pole can create excess phase shift and even oscillation. A small capacitor,  $C_{FB}$ , in parallel and  $R_{FB}$  eliminates this problem. By setting  $R_S$  ( $C_S+C_{\rm IN}$ ) =  $R_{FB}C_{FB}$ , the effect of the feedback pole is completely removed.

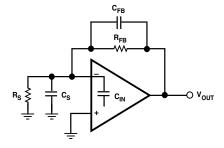


Figure 14. Compensating the Feedback Pole

#### **Attention to Source Impedances Minimizes Distortion**

Since the OP275 is a very low distortion amplifier, careful attention should be given to source impedances seen by both inputs. As with many FET-type amplifiers, the p-channel JFETs in the OP275's input stage exhibit a gate-to-source capacitance that varies with the applied input voltage. In an inverting configuration, the inverting input is held at a virtual ground and, as such, does not vary with input voltage. Thus, since the gate-to-source voltage is constant, there is no distortion due to input capacitance modulation. In noninverting applications, however, the gate-to-source voltage is not constant. The resulting capacitance modulation can cause distortion above 1 kHz if the input impedance is greater than 2 k $\Omega$  and unbalanced.

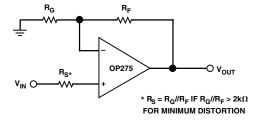


Figure 15. Balanced Input Impedance to Minimize Distortion in Noninverting Amplifier Circuits

Figure 15 shows some guidelines for maximizing the distortion performance of the OP275 in noninverting applications. The best way to prevent unwanted distortion is to ensure that the parallel combination of the feedback and gain setting resistors ( $R_{\rm F}$  and  $R_{\rm G}$ ) is less than 2 k $\Omega$ . Keeping the values of these resistors small has the added benefits of reducing the thermal noise of the circuit

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and dc offset errors. If the parallel combination of  $R_F$  and  $R_G$  is larger than 2 k $\Omega$ , then an additional resistor,  $R_S$ , should be used in series with the noninverting input. The value of  $R_S$  is determined by the parallel combination of  $R_F$  and  $R_G$  to maintain the low distortion performance of the OP275.

#### **Driving Capacitive Loads**

The OP275 was designed to drive both resistive loads to  $600~\Omega$  and capacitive loads of over 1000 pF and maintain stability. While there is a degradation in bandwidth when driving capacitive loads, the designer need not worry about device stability. The graph in Figure 16 shows the 0 dB bandwidth of the OP275 with capacitive loads from 10 pF to 1000 pF.

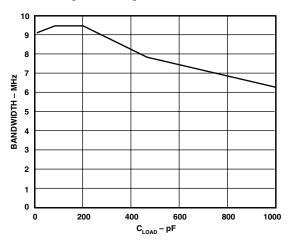


Figure 16. Bandwidth vs.  $C_{LOAD}$ 

#### High Speed, Low Noise Differential Line Driver

The circuit in Figure 17 is a unique line driver widely used in industrial applications. With  $\pm 18\,V$  supplies, the line driver can deliver a differential signal of 30 V p-p into a 2.5 k $\Omega$  load. The high slew rate and wide bandwidth of the OP275 combine to yield a full power bandwidth of 130 kHz while the low noise front end produces a referred-to-input noise voltage spectral density of 10 nV/ $\sqrt{Hz}$ .

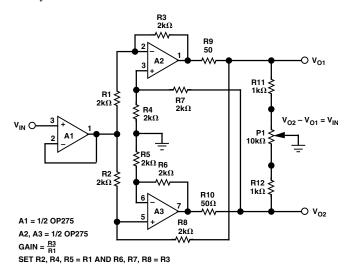


Figure 17. High Speed, Low Noise Differential Line Driver

The design is a transformerless, balanced transmission system where output common-mode rejection of noise is of paramount importance. Like the transformer based design, either output can be shorted to ground for unbalanced line driver applications without changing the circuit gain of 1. Other circuit gains can be set according to the equation in the diagram. This allows the design to be easily set to noninverting, inverting, or differential operation.

#### A 3-Pole, 40 kHz Low-Pass Filter

The closely matched and uniform ac characteristics of the OP275 make it ideal for use in GIC (Generalized Impedance Converter) and FDNR (Frequency-Dependent Negative Resistor) filter applications. The circuit in Figure 18 illustrates a linear-phase, 3-pole, 40 kHz low-pass filter using an OP275 as an inductance simulator (gyrator). The circuit uses one OP275 (A2 and A3) for the FDNR and one OP275 (A1 and A4) as an input buffer and bias current source for A3. Amplifier A4 is configured in a gain of 2 to set the pass band magnitude response to 0 dB. The benefits of this filter topology over classical approaches are that the op amp used in the FDNR is not in the signal path and that the filter's performance is relatively insensitive to component variations. Also, the configuration is such that large signal levels can be handled without overloading any of the filter's internal nodes. As shown in Figure 19, the OP275's symmetric slew rate and low distortion produce a clean, well behaved transient response.

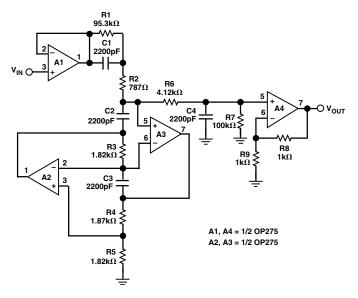


Figure 18. A 3-Pole, 40 kHz Low-Pass Filter

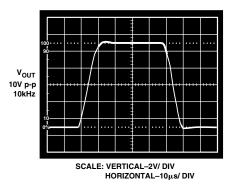


Figure 19. Low-Pass Filter Transient Response

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```
OP275 SPICE Model
                                                          * POLE/ZERO PAIR AT 1.5 MHz/2.7 MHz
* Node assignments
                                                                    98
                                                          R8
                                                                 21
                                                                          1E-3
                noninverting input
                                                          R9
                                                                 21
                                                                     22
                                                                          1.25E-3
                     inverting input
                                                          C4
                                                                     98
                                                                          47.2E-12
                                                                 22
                                                                                   28
                         positive supply
                                                          G2
                                                                 98
                                                                     21
                                                                          18
                                                                                         1E-3
                              negative supply
                                                          * POLE AT 100 MHz
                                    output
.SUBCKT OP275 1
                     2
                         99
                               50
                                                          R10 23 98 1
                                                                 23 98
                                                          C5
                                                                          1.59E-9
* INPUT STAGE & POLE AT 100 MHz
                                                          G3
                                                                 98 23
                                                                                   28
                                                                          21
                                                                                         1
R3
                2.188
                                                          * POLE AT 100 MHz
       5
           51
R4
       6
           51
                2.188
           2
                3.7E-12
                                                          R11 24 98 1
CIN
       1
                7.5E-12
                                                                24 98
CM1
       1
           98
                                                          C6
                                                                          1.59E-9
CM2
       2
           98
                7.5E-12
                                                          G4
                                                                 98 24
                                                                          23
                                                                                   28
                                                                                         1
C2
       5
           6
                364E-12
I1
       97
           4
                100E-3
                                                          * COMMON-MODE GAIN NETWORK WITH ZERO AT
                                                          1 kHz
IOS
       1
           2
                1E-9
EOS
       9
                POLY(1) 26
                                     0.5E-3 1
                               28
           3
01
       5
           2
                7
                         OX
                                                          R12 25 26 1E6
                                                          C7 25 26 1.5915E-12
Q2
       6
           9
                8
                         QX
                                                          R13 26 98 1
R5
       7
           4
                1.672
R6
                1.672
                                                          E2
                                                               25 98
                                                                                              2 98
       8
                                                                          POLY(2) 1 98
                                                                                                        0 2.50
           4
       2
                DZ
                                                          2.50
D1
           36
D2
       1
           36
                DZ
EN
       3
                10
                         0
                               1
                                                          * POLE AT 100 MHz
           1
                               1E-3
GN1
       0
           2
                13
                         0
GN2
       0
                16
                         Ω
                               1E-3
                                                          R14 27 98 1
           1
                                                          C8
                                                                 27 98
                                                                          1.59E-9
EREF
       98
           0
                28
                         0
                                                          G5
                                                                 98 27
                                                                          24
                                                                                   28
                               1
ΕP
       97
           0
                99
                         0
                               1
EM
       51
           0
                50
                         0
                               1
                                                          * OUTPUT STAGE
* VOLTAGE NOISE SOURCE
                                                          R15
                                                                 28
                                                                     99
                                                                          100E3
                                                          R16
                                                                     50
                                                                          100E3
DN1
       35
           10
                DEN
                                                          C9
                                                                 28
                                                                     50
                                                                          1E-6
                                                          ISY
DN2
       10
           11
                DEN
                                                                 99
                                                                     50
                                                                          1.85E-3
VN1
           0
                DC
                                                                 29
                                                                     99
       35
                         2
                                                          R17
                                                                          100
           11
                                                          R18
                                                                 29
                                                                     50
VN2
                DC
                                                                           100
                                                          L2
                                                                 29
                                                                     34
                                                                           1E-9
* CURRENT NOISE SOURCE
                                                          G6
                                                                 32
                                                                     50
                                                                           27
                                                                                    29
                                                                                         10E-3
                                                          G7
                                                                 33
                                                                     50
                                                                           29
                                                                                   27
                                                                                         10E-3
DN3
       12
           13
                DIN
                                                          G8
                                                                 29
                                                                     99
                                                                           99
                                                                                   27
                                                                                         10E-3
                                                                           27
DN4
      13
           14
                DIN
                                                          G9
                                                                 50
                                                                     29
                                                                                         10E-3
VN3
       12
           0
                DC
                         2
                                                          V4
                                                                 30
                                                                     29
                                                                           1.3
       Ω
           14
                DC
                                                          V5
                                                                 29
                                                                           3.8
VN4
                                                                     31
                                                          F1
                                                                 29
                                                                     0
                                                                           V4
                                                                                   1
* CURRENT NOISE SOURCE
                                                          F2
                                                                 0
                                                                     29
                                                                           V5
                                                                                    1
                                                          D5
                                                                 27
                                                                     30
                                                                           DX
DN5
       15
           16
                DIN
                                                          D6
                                                                 31
                                                                     27
                                                                           DX
DN6
       16
           17
                DIN
                                                          D7
                                                                 99
                                                                     32
                                                                          DX
                DC
                                                                     33
VN5
       15
           Ω
                         2
                                                          D8
                                                                 99
                                                                          DΧ
VN6
           17
                DC
                         2
                                                          D9
                                                                 50
                                                                     32
                                                                          DY
                                                          D10
                                                                 50
* GAIN STAGE & DOMINANT POLE AT 32 Hz
                                                          * MODELS USED
R7
       18
           98
                1.09E6
           98
                4.55E-9
                                                                        PNP(BF=5E5)
C3
       18
                                                          .MODEL QX
G1
       98
           18
                5
                              4.57E-1
                                                          .MODEL DX
                                                                        D(IS=1E-12)
                         6
V2
       97
           19
                1.35
                                                          .MODEL DY
                                                                        D(IS=1E-15 BV=50)
                                                          .MODEL DZ
                                                                        D(IS=1E-15 BV=7.0)
V3
       20
           51
                1.35
                DX
                                                          .MODEL DEN
                                                                        D(IS=1E-12 RS=4.35K KF=1.95E-15
D3
       18
           19
D4
       20
           18
                DX
                                                          AF=1)
                                                          .MODEL DIN
                                                                        D(IS=1E-12 RS=268 KF=1.08E-15 AF=1)
                                                          .ENDS
```

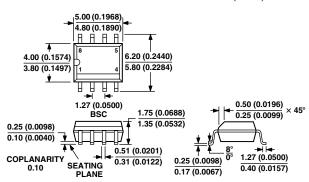
# C00298-0-2/04(C)

#### **OUTLINE DIMENSIONS**

### 8-Lead Standard Small Outline Package [SOIC]

(S Suffix) (R-8)

Dimensions shown in millimeters and (inches)



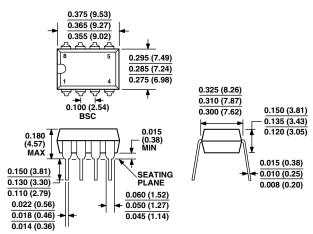
#### COMPLIANT TO JEDEC STANDARDS MS-012AA

CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

#### 8-Lead Plastic Dual-in-Line Package [PDIP] (P Suffix)

(N-8)

Dimensions shown in inches and (millimeters)



#### COMPLIANT TO JEDEC STANDARDS MO-095AA

CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

# **Revision History**

Location	Page
2/04—Data Sheet changed from REV. B to REV. C.	
Changes to ABSOLUTE MAXIMUM RATINGS	
Changes to ORDERING GUIDE	
Updated OUTLINE DIMENSIONS	
1/03—Data Sheet changed from REV. A to REV. B.	
Deleted WAFER TEST LIMITS	
Edits to ABSOLUTE MAXIMUM RATINGS	
Edits to ORDERING GUIDE	
Deleted DICE CHARACTERISTICS	
Updated OUTLINE DIMENSIONS	